

Space Charge Effects on the Evolution of Short Pulse Beam Profiles

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Summary

- We investigate **space charge effects** on the dynamics of short pulse beam profile.
- We consider **short pulses** of different profiles for different charge densities and pulse widths.
- We analyze the electron sheet **phase-space trajectories** and pulse profile evolution during gap transit.

Multiple-Sheet Model

A one-dimensional (1D) planar diode with gap distance d and gap voltage V_g , with M sheets inside.

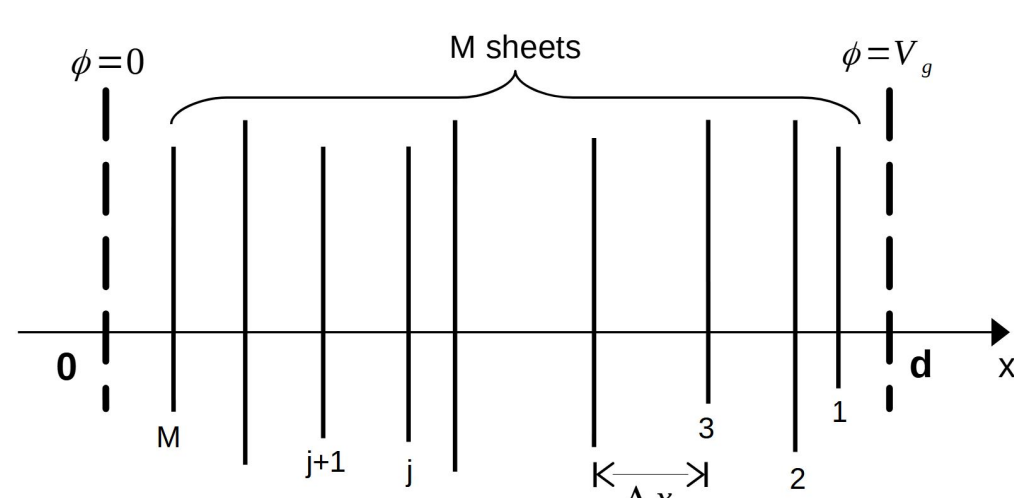


Figure 1: Sheet numbering inside the diode gap [1]

- Sheet j at position $\bar{x}_j = x_j/d$ has a normalized charge density $\bar{\rho}_j = \rho/\sigma_1$.
- The normalized electric field on sheet j is

$$\bar{E}_j = \frac{E_j}{E_0} = 1 + \left[\sum_{i=1}^M \bar{\rho}_i \bar{x}_i - \left(\sum_{i=1}^{j-1} \bar{\rho}_i + \frac{1}{2} \bar{\rho}_j \right) \right] \quad (1)$$

- The normalized Electric field at the cathode ($\bar{x} = 0$)

$$\bar{E}_K = 1 + \sum_{i=1}^M \bar{\rho}_i (\bar{x}_i - 1) \quad (2)$$

- The Space Charge Limited (SCL) charge density $\bar{\rho}_j^*$ is found for $\bar{E}_K = 0$

$$1 + \sum_{i=1}^M \bar{\rho}_i^* (\bar{x}_i - 1) = 0 \quad (3)$$

Model Parameters

Symbol	Meaning	Formula/Value
E_0	Applied field	$-V_g/d$
σ_1	SCL density	$\varepsilon_0 E_0$
τ_p	Pulse length	$[0.1, 1] \times T_0$
T_0	Transit time	$\sqrt{2d/(eE_0/m)}$
Δ	Distortion	$\delta\bar{x}_{final}/\delta\bar{x}_{init}$
J	Current density	$J = 3 \sum_{i=1}^M \bar{\rho}_i \bar{v}_i$

Square-top Profile

- All sheets have **equal charge density** $\bar{\rho}$
- The SCL charge density $\bar{\rho}^*$ is found from (3)

$$\bar{\rho}^* = \frac{1}{M} \left[\frac{1}{1 - \delta\bar{x} \left(\frac{M-1}{2} \right)} \right] \quad (4)$$

- We simulate 30 preloaded sheets inside the gap. The initial pulse intervals $\delta\bar{x} = \bar{x}_n - \bar{x}_{n+1}$ are assumed to be uniform. $\delta\bar{x} \approx (1/2)(eE_0/m)\tau_p^2$ where τ_p is the pulse time length.

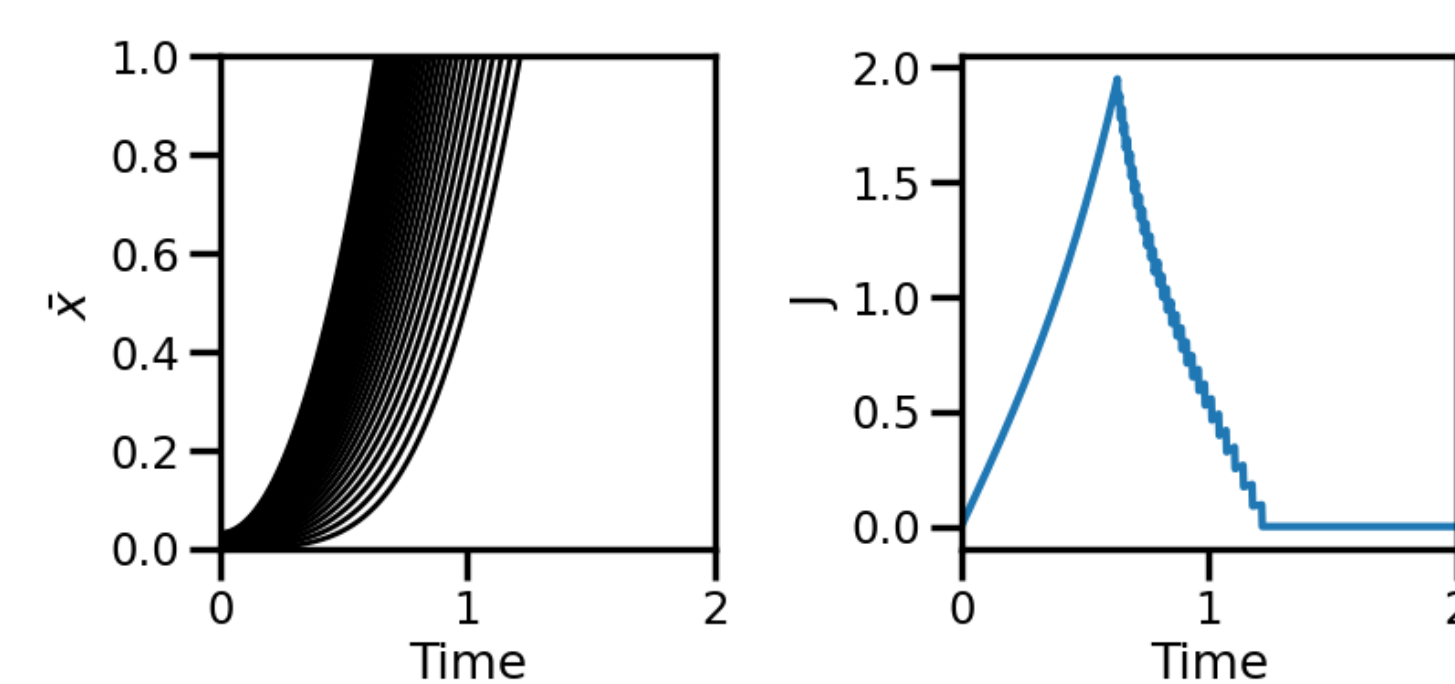


Figure 2: Sheets' trajectories & current density for T_0 and $\bar{\rho}^*$

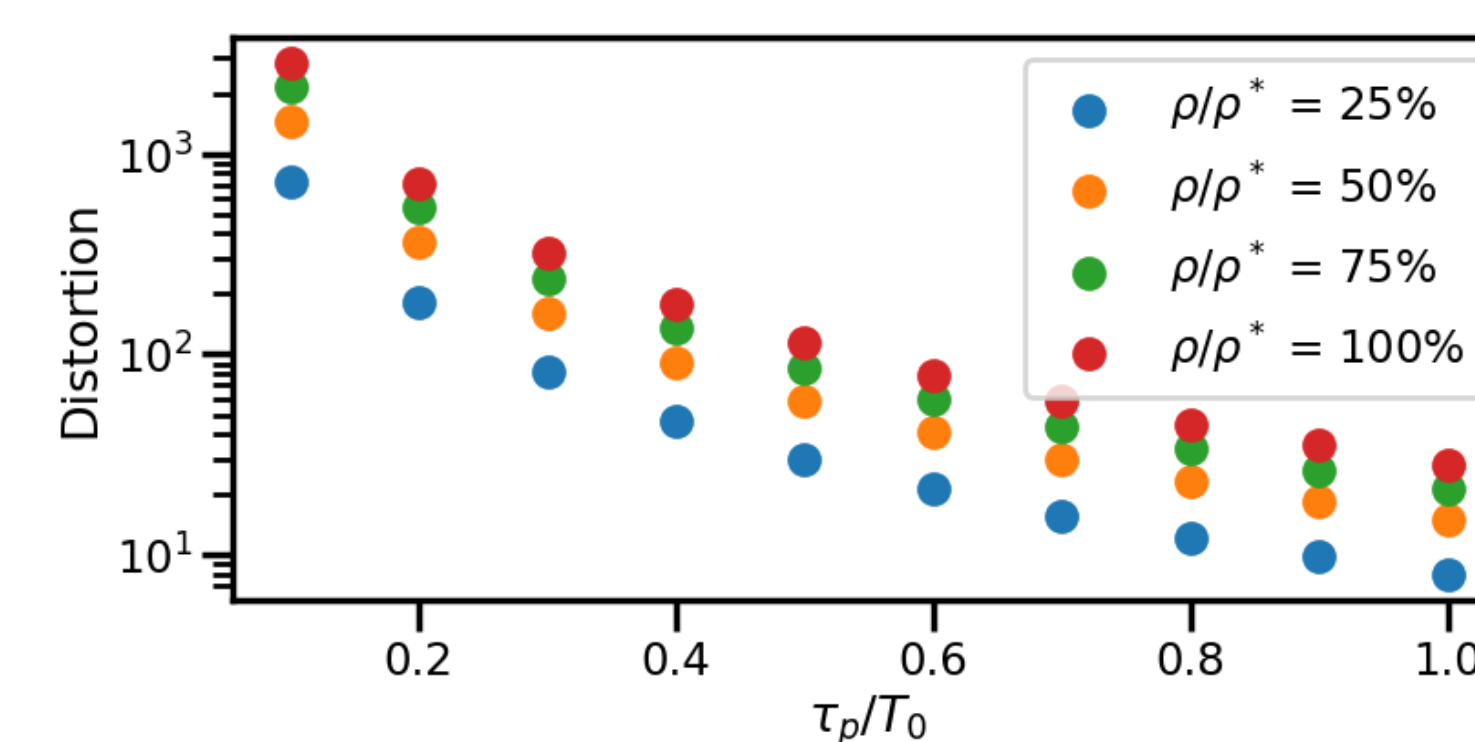


Figure 3: Square-top profile distortion with initial pulse length

Gaussian Profile

- Sheet j has a **charge density**

$$\bar{\rho}_j = a \exp \left[-\frac{(j - \mu)^2}{b} \right] \quad (5)$$

where $\mu = (M+1)/2$, a and b are found by solving (3) with $\sum_{i=1}^M \bar{\rho}_i^* = 1$ (as the bulk of sheets tends to combine, looking like a single sheet).

- We simulate for $M = 30$ preloaded sheets, $a = 1/12.5$, and $b = 50$.

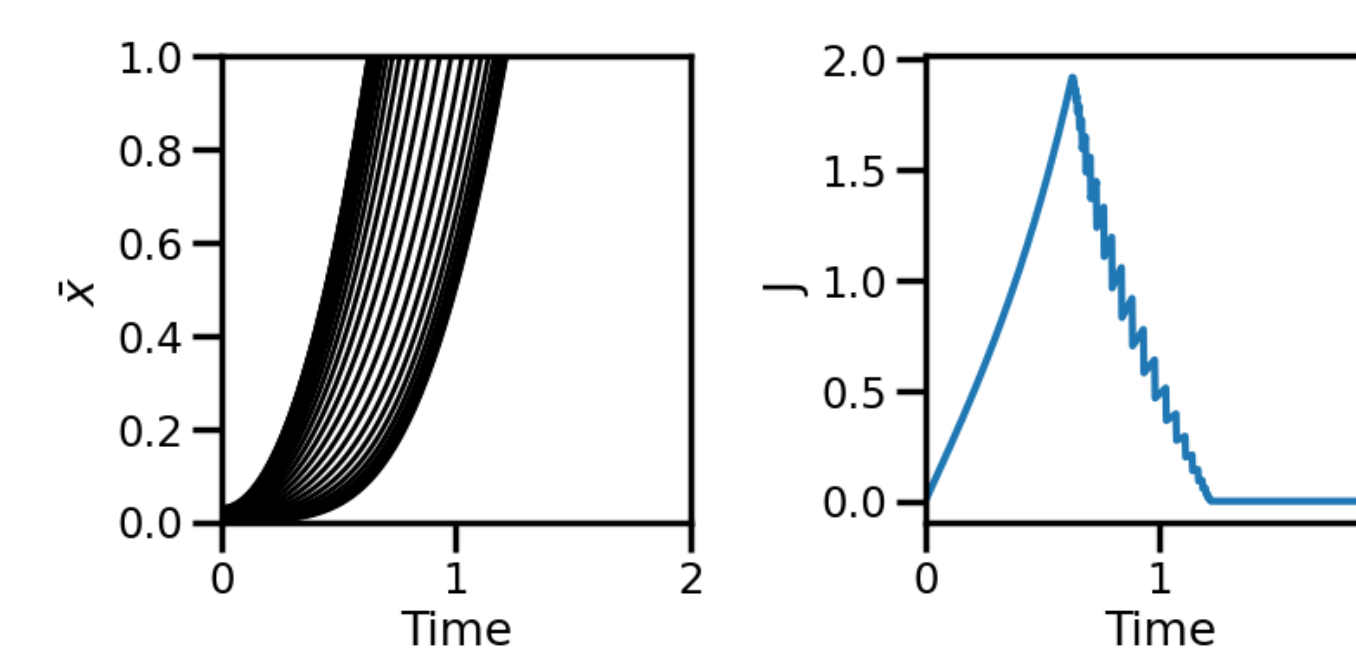


Figure 4: Sheets' trajectories & current density for T_0 and $\bar{\rho}^*$

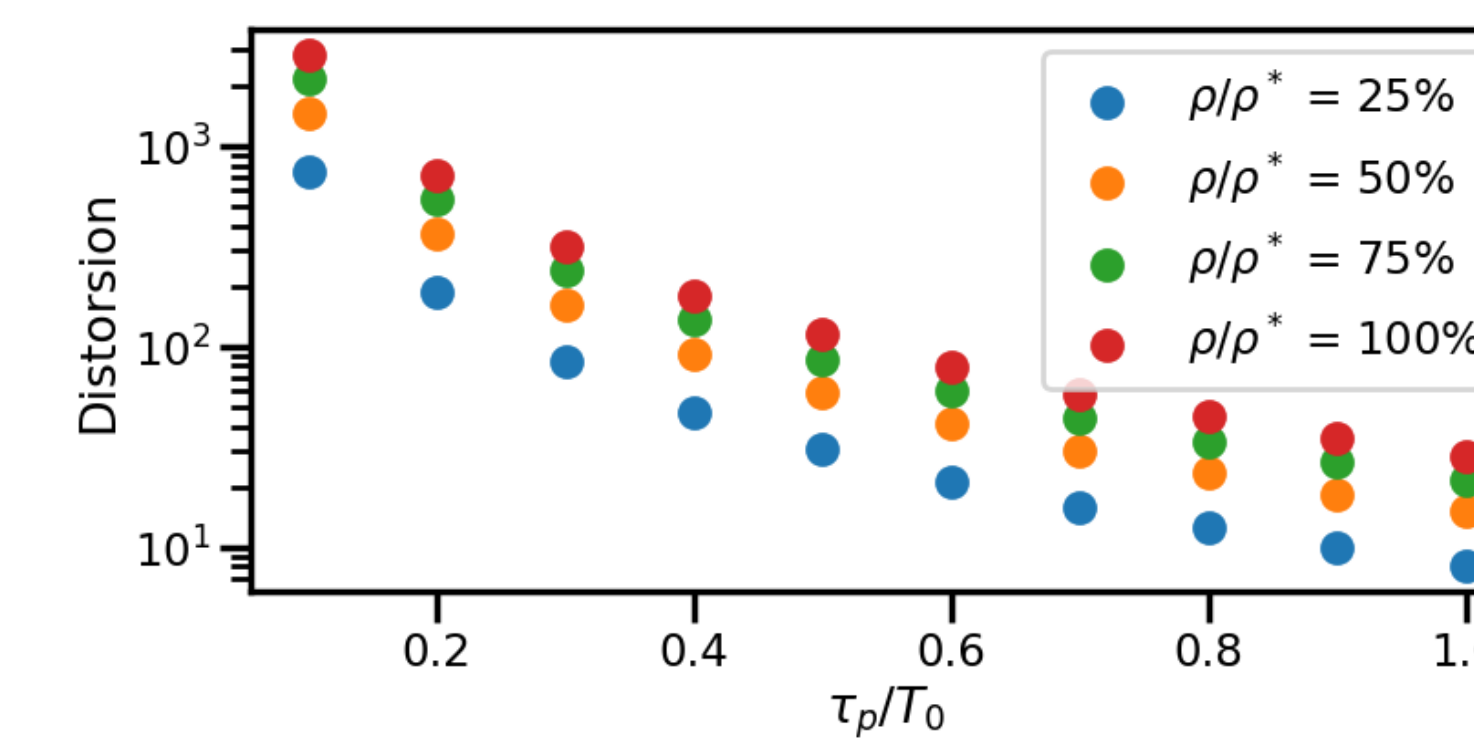


Figure 5: Gaussian profile distortion with initial pulse length

Evolution of the Gaussian Pulse Profiles Inside the Gap

- We simulate Gaussian pulses with $M = 30$ preloaded sheets. We fixed $\delta\bar{x} = 1/M^2 = 1/900$ and $\bar{x}_{30} = 0$.

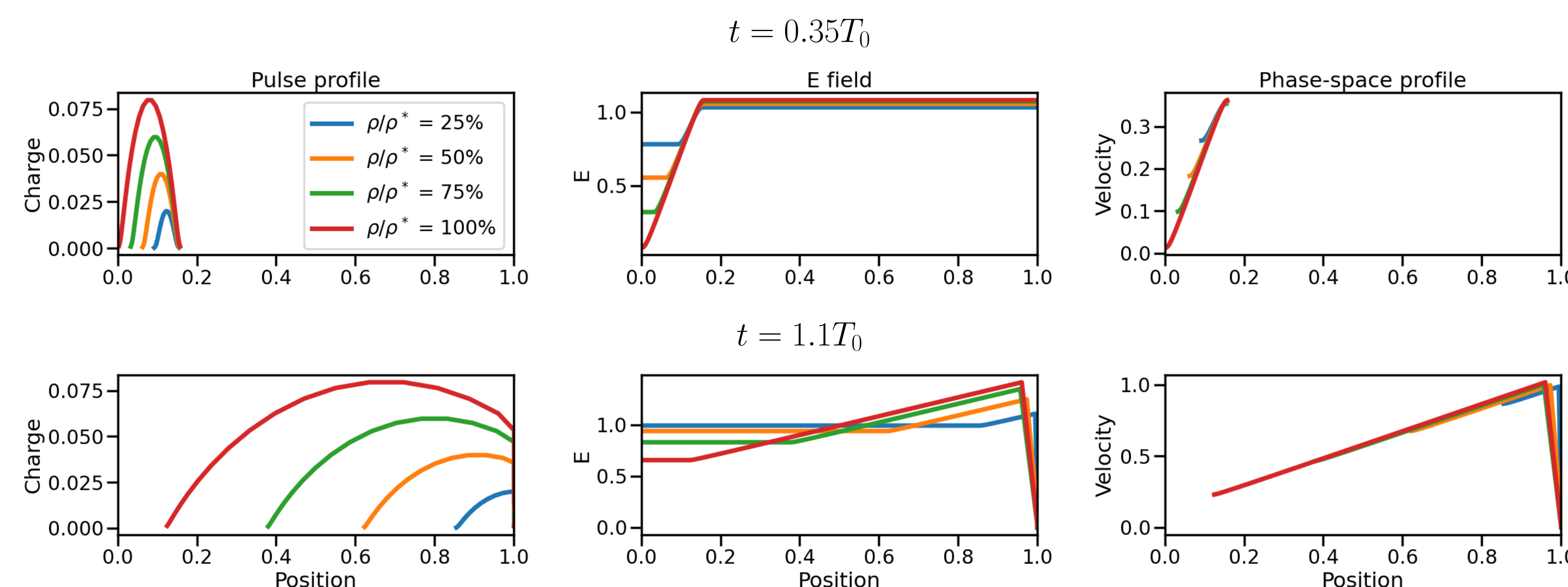


Figure 6: Snapshots of the evolution of pulse profile, electric field, and velocity for $\bar{\rho}_j = 25, 50, 75$ and 100% of $\bar{\rho}_j^*$

Algorithm 1 Calculation of distortion

Input: $M, \delta\bar{x}$

- 1: $\delta\bar{x}_{init} \leftarrow (M-1)\delta\bar{x}$
- 2: $t \leftarrow 0$
- 3: **while** $\bar{x}_1(t) < 1$ **do**
- 4: $t \leftarrow t + 1$
- 5: **end while**
- 6: $\delta\bar{x}_{final} \leftarrow \bar{x}_1(t) - \bar{x}_M(t)$
- 7: $\Delta \leftarrow \delta\bar{x}_{final}/\delta\bar{x}_{init}$
- 8: **return** Δ

Conclusion & Future Work

- 1 For the **same total charge**, square-top and Gaussian pulses undergo **similar distortion** (fig. 3 and 5).
- 2 The **shorter** the pulse length, the **more significant the distortion** becomes.
- 3 The **smaller the charge**, the **faster the tail** of the pulse travels through the gap (fig. 6).
- 4 In future work, we will **assess the Child-Langmuir limit** as the pulse length decreases.

References & Acknowledgement

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Acknowledgement: Work is supported by the Office of Naval Research (ONR) YIP Grant No. N00014-20-1-2681, the Air Force Office of Scientific Research (AFOSR) Grant No. FA9550-20-1-0409, and the Air Force Office of Scientific Research (AFOSR) Award No. FA9550-22-1-0523

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